

Enhanced ultrafast power diode Rev.02 - 21 February 2024

Product data sheet

1. General description

Enhanced ultrafast power diode in a SOT404 (D2PAK) surface-mountable plastic package.

2. Features and benefits

- High thermal cycling performance
- Low on-state losses
- Low thermal resistance
- Soft recovery characteristic
- Surface-mountable package

3. Applications

- Dual Mode (DCM and CCM) PFC
- Power Factor Correction (PFC) for Interleaved Topology

4. Quick reference data

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Symbol	Parameter	Conditions	Mir	n Typ	Max	Unit
V _R	reverse voltage	DC	-	-	600	V
I _{F(AV)}	average forward current	$\delta = 0.5$; T _{mb} \leq 115 °C; SQW; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	-	9	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_{p} = 25 µs; T_{mb} ≤ 115 °C; SQW	-	-	18	A
I _{FSM}	non-repetitive peak	t _p = 10 ms; T _{j(init)} = 25 °C; SIN; <u>Fig. 3</u>	-	-	91	А
	forward current	t _p = 8.3 ms; T _{j(init)} = 25 °C; SIN; <u>Fig. 3</u>	-	-	100	А
Static chara	acteristics					
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.45	1.9	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.25	1.7	V
Dynamic ch	naracteristics	·			·	
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _i = 25 °C; <u>Fig. 6</u>	-	17.5	35	ns

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		
2	К	cathode		К — С — А 001ааа020
3	А	anode	<u> </u> <u></u>	
mb	К	mounting base; connected to cathode	$ \begin{bmatrix} & & \\ &$	

[1] it is not possible to make connection to Pin 2 of the TO263 package.

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYV29FB-600	TO263	BYV29FB-600,118	Reel	800	TO263N (N)	26-Sep-2016
					TO263P (P)	12-Jun-2023

7. Marking

Table 4. Marking codes					
Marking codes					
Assembly factory: N	Assembly factory: P				
BAV29FB 600 PINYYY YY	BYV29FB 600 PJPxxxx xx				
	Assembly factory: N BAV29FB				

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ;T _{mb} ≤ 115 °C; SQW; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	9	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 µs; T _{mb} ≤ 115 °C; SQW	-	18	A
I _{FSM}	non-repetitive peak	t _p = 10 ms; T _{j(init)} = 25 °C; SIN; <u>Fig. 3</u>	-	91	А
	forward current	t _p = 8.3 ms; T _{j(init)} = 25 °C; SIN; <u>Fig. 3</u>	-	100	А
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

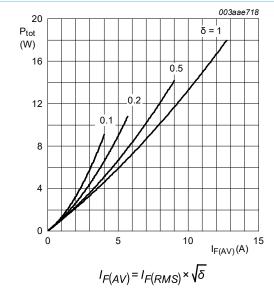


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

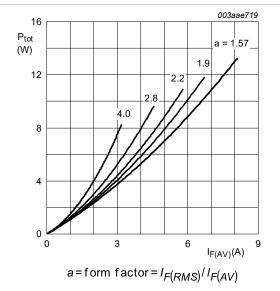
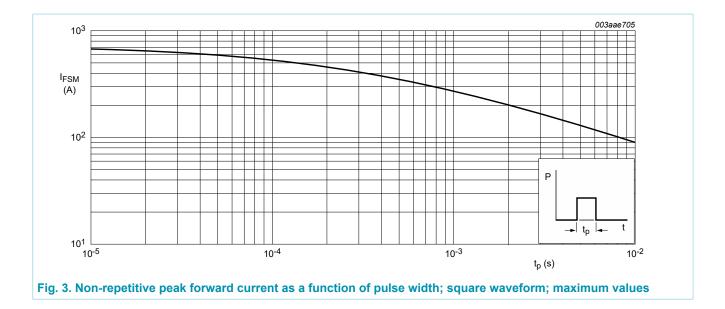


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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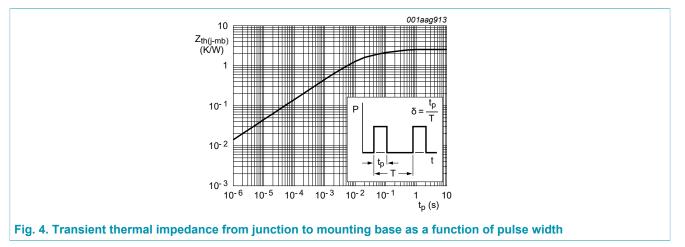
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8. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4		-	-	2.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	[1]	-	50	-	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

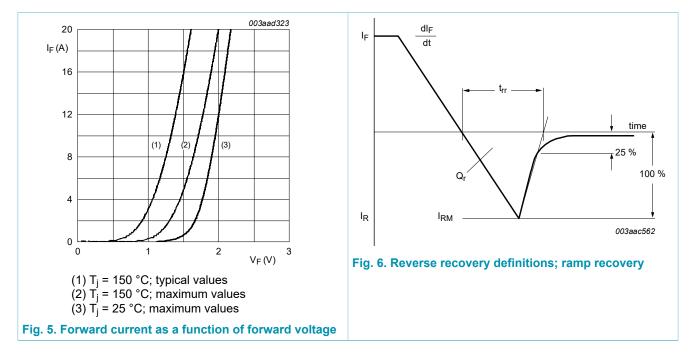


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9. Characteristics

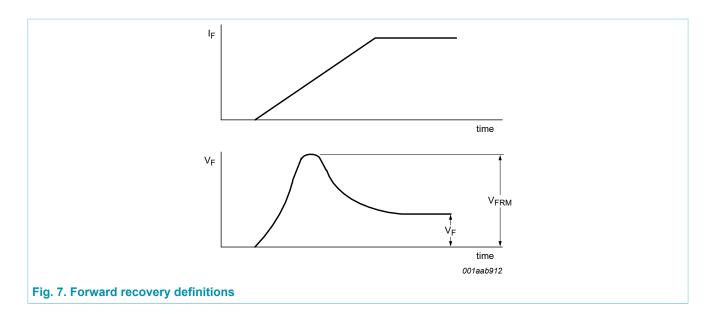
Table 6. Cha	aracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.45	1.9	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.25	1.7	V
I _R	reverse current	V _R = 600 V; T _j = 100 °C	-	-	1.5	mA
		V _R = 600 V; T _j = 25 °C	-	-	50	μA
Dynamic ch	naracteristics	· · · · ·				
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 6$	-	17.5	35	ns
I _{RM}	peak reverse recovery current	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	1.5	-	A
Q _r	recovered charge		-	13	-	nC
$V_{\sf FR}$	forward recovery voltage	I _F = 1 A; dI _F /dt = 100 A/μs; <u>Fig. 7</u>	-	3.2	-	V



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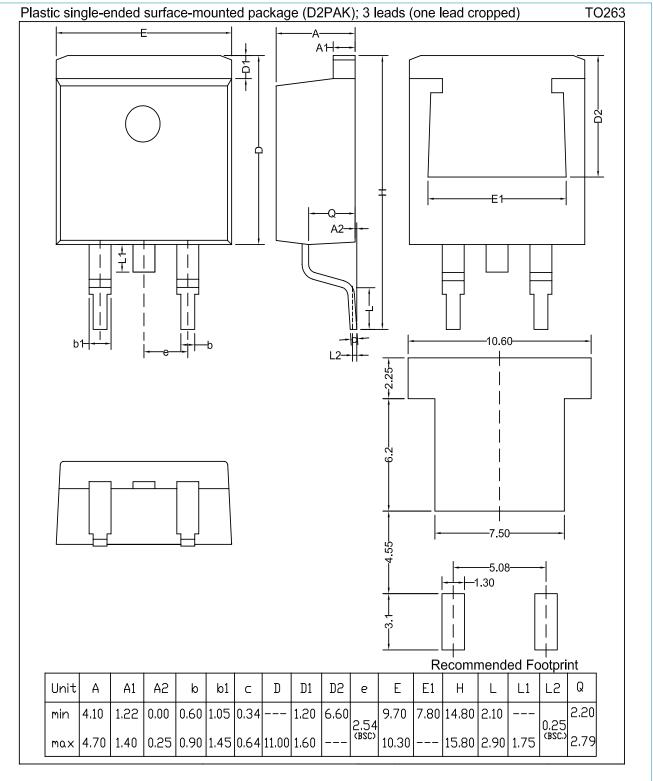
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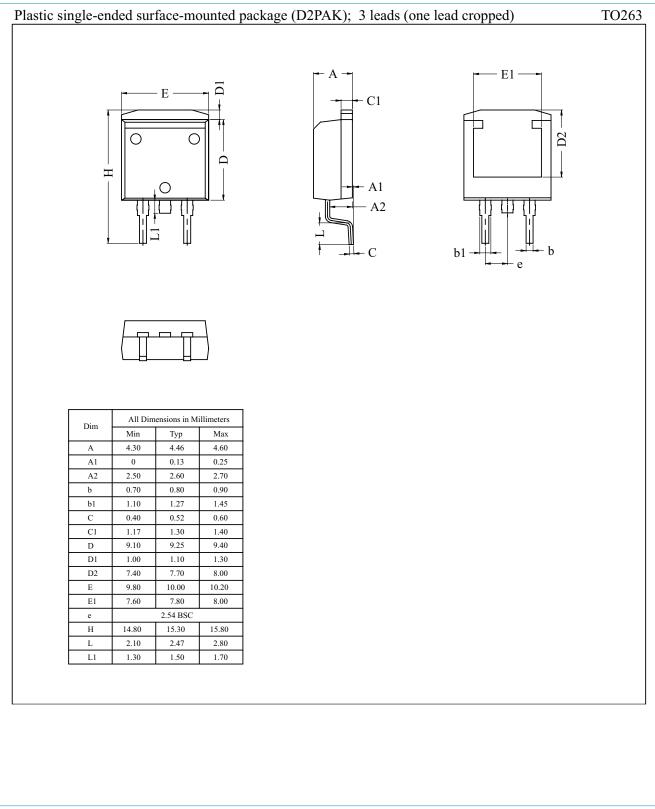
10. Package outline

Assembly factory: N



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Assembly factory: P



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11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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